

TOSHIBA Digital Integrated Circuit Silicon Monolithic

T3GE9WBG

Dual Supply Bus Transceiver for SD Card

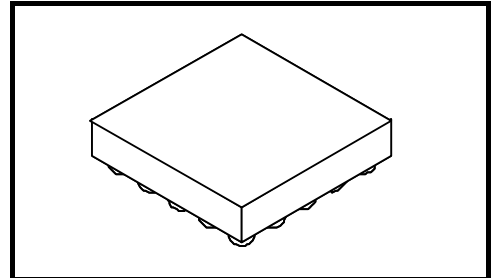
The T3GE9WBG is a dual supply, advanced high-speed CMOS dual supply voltage interface bus transceiver fabricated with silicon gate CMOS technology.

Designed for use as an interface between a 1.8-V bus and a 2.9-V bus in mixed 1.8-V/2.9-V supply systems.

The A-port interfaces with the 1.8-V bus, the B-port with the 2.9-V bus.

The direction of data transmission is determined by the level of the DIR input.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.



Weight: 0.006 g (typ.)

Features

Bidirectional interface between 1.8-V and 2.9-V buses.

High-speed operation : $t_{pd} = 8.5 \text{ ns (max)}$ ($V_{CCA} = 1.8 \pm 0.15 \text{ V}$, $V_{CCB} = 2.9 \pm 0.1 \text{ V}$)

Output current : $I_{OHB}/I_{OLB} = \pm 6 \text{ mA (min)}$ ($V_{CCB} = 2.8 \text{ V}$)
 $I_{OHA}/I_{OLA} = \pm 6 \text{ mA (min)}$ ($V_{CCA} = 1.65 \text{ V}$)

Regulator output current: 200mA (min)

Integrated EMI filter on B-port

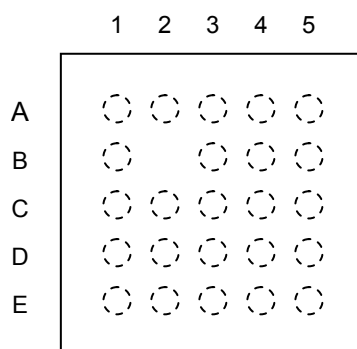
Integrated Pull-up and Pull-down resistors on B-port

Latch-up performance : $\pm 200 \text{ mA}$

ESD performance : Machine model $> \pm 200 \text{ V}$
Human body model $> \pm 2000 \text{ V}$
IEC61000-4-2 Level 4 (Contact) $> \pm 8000 \text{ V}$ (SD card side)

Ultra-small package : WCSP24

Pin Assignment (top view)



(Top view)

	1	2	3	4	5
A	Dat2.h	CMD-dir	Dat0-dir	V _{Batt}	Dat2-B
B	Dat3.h	--	V _{CCA}	V _{CCB} O/P	Dat3-B
C	Clk.h	Enable	GND	GND	CLK-B
D	Dat0.h	CMD.h	CD	CMD-B	Dat0-B
E	Dat1.h	Clk-f	Dat123-dir	WP	Dat1-B

Truth Table

Input	Outputs	
Clk.h	Clk-f	CLK-B
L	L	L
H	H	H

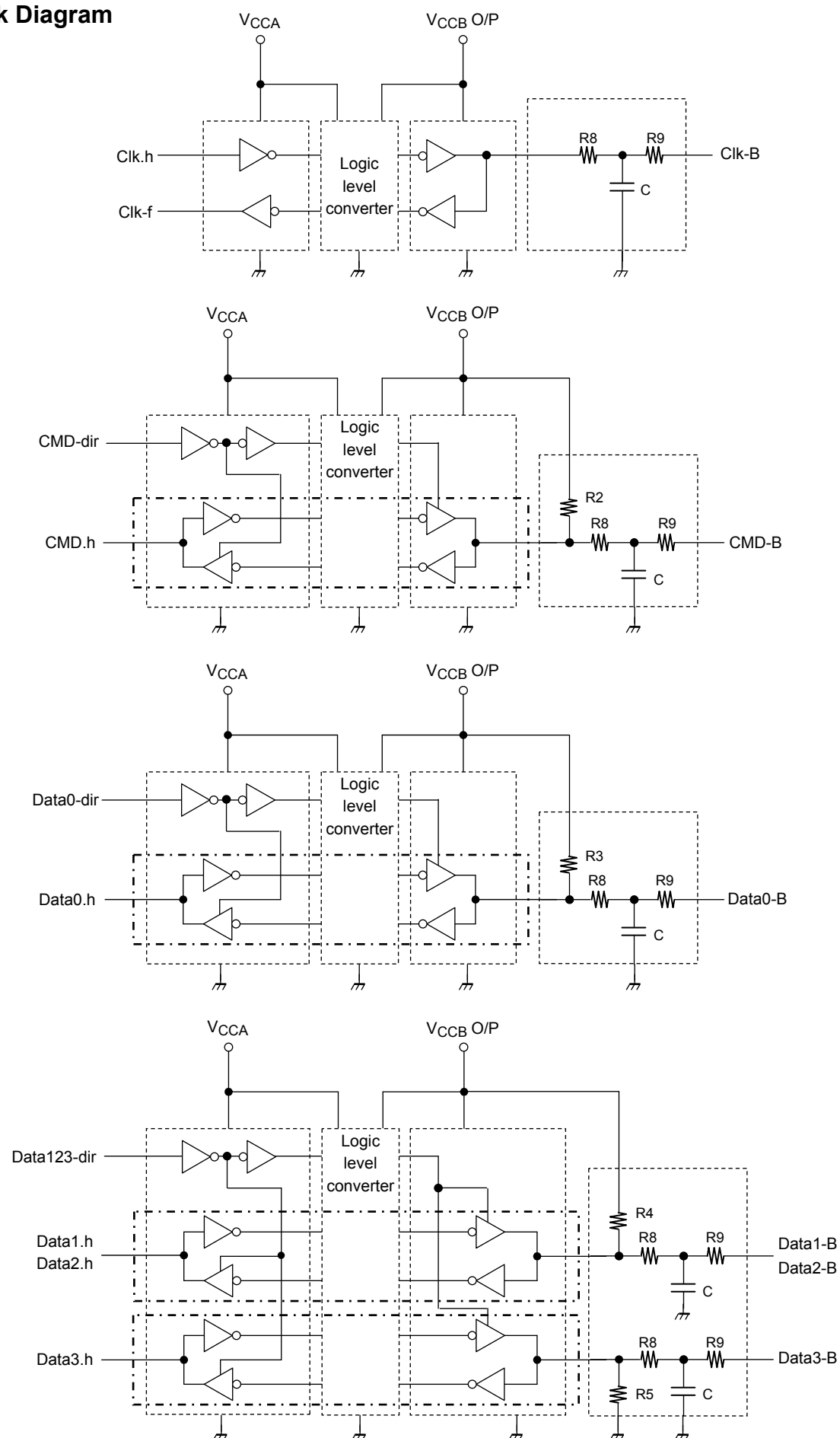
Inputs	Function		Outputs
CMD-dir	CMD.h	CMD-B	
L	Output	Input	CMD.h = CMD-B
H	Input	Output	CMD-B = CMD.h

Inputs	Function		Outputs
Dat0-dir	Dat0.h	Dat0-B	
L	Output	Input	Dat0.h = Dat0-B
H	Input	Output	Dat0-B = Dat0.h

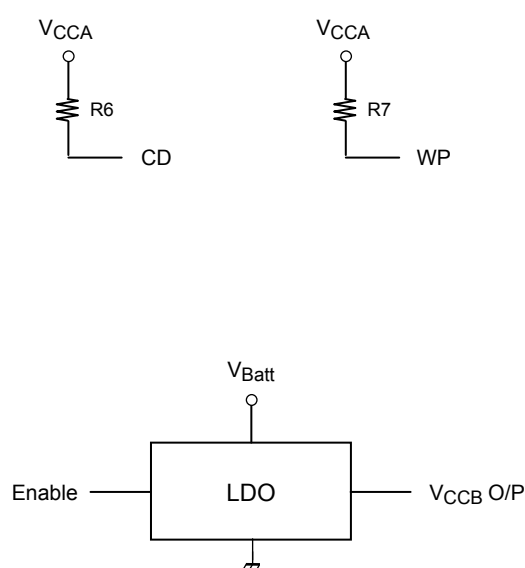
Inputs	Function		Outputs
Dat123-dir	Dat1.h – Dat3.h	Dat1-B – Dat3-B	
L	Output	Input	Datn.h = Datn-B
H	Input	Output	Datn-B = Datn.h

Input	Output
Enable	Regulator
L	OFF
H	ON

Block Diagram



Block Diagram



Symbol	Value (typ)
R3, R4	70k Ω
R2	15k Ω
R5	470k Ω
R6, R7	100k Ω
R8	5 Ω
R9	35 Ω
C	35pF

Absolute Maximum Ratings (Note 1)

Characteristics		Symbol	Rating	Unit
Power supply voltage		V _{CCA}	-0.5 to 3.0	V
		V _{Batt}	5.5	
DC input voltage	DIR, Clk.h	V _{IN}	-0.5 to V _{CCA} + 0.5	V
	Enable		-0.5 to 5.5	
DC bus I/O voltage		V _{I/OA}	-0.5 to V _{CCA} + 0.5 (Note 2)	V
		V _{I/OB}	-0.5 to V _{CCB} + 0.5 (Note 2)	
Input diode current	DIR, Clk.h	I _{IK}	± 25	mA
	Enable		-25	
Output diode current		I _{I/OK}	± 25 (Note 3)	mA
DC output current		I _{OUTA}	± 25	mA
		I _{OUTB}	± 25	
DC V _{CC} /ground current per supply pin		I _{CCA}	± 50	mA
Power dissipation		P _D	400	mW
Storage temperature		T _{stg}	-55 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Note 2: High or Low stats. I_{OUT} absolute maximum rating must be observed.

Note 3: V_{OUT} < GND, V_{OUT} > V_{CC}

Operating Range (Note 1)

Characteristics		Symbol	Rating	Unit
Power supply voltage		V_{CCA}	1.65 to 1.95	V
		V_{Batt}	3.2 to 5.0	
Input voltage	DIR, Clk.h	V_{IN}	0 to V_{CCA}	V
	Enable		0 to 5.0	
Bus I/O voltage		V_{IOA}	0 to V_{CCA} (Note 2)	V
		V_{IOB}	0 to V_{CCB} O/P (Note 2)	
Output current		I_{OUTA}	± 6 (Note 3)	mA
		I_{OUTB}	± 6 (Note 4)	
Operating temperature		T_{opr}	-30 to 85	°C
Input rise and fall time		dt/dv	0 to 10 (Note 5)	ns/V

Note 1: The operating range is required to ensure the normal operation of the device. Unused inputs and bus inputs must be tied to either VCC or GND. Please connect both bus inputs and the bus outputs with VCC or GND when the I/O of the bus terminal changes by the function. In this case, please note that the output is not short-circuited.

Note 2: High or low state

Note 3: $V_{CCA} = 1.65$ to 1.95 V

Note 4: $V_{CCB} = 2.8$ to 3.0 V, V_{CCB} is supplied from the built-in LDO.

Note 5: $V_{CCA} = 1.65$ V, $V_{CCB} = 2.8$ V

Electrical Characteristics
DC Characteristics ($1.65\text{ V} \leq V_{CCA} \leq 1.95\text{ V}$, $2.8\text{ V} \leq V_{CCB} \leq 3.0\text{ V}$)

Characteristics	Symbol	Test Condition		V _{CCA} (V)	V _{CCB} (V)	Ta = −30 to 85°C		Unit
						Min	Max	
H-level input voltage	V _{IHA}	DIR, An (Note 1)		1.65 to 1.95	2.8 to 3.0	V _{CCA} ×0.65	—	V
	V _{IHB}	Bn (Note 1)		1.65 to 1.95	2.8 to 3.0	2.0	—	
L-level input voltage	V _{ILA}	DIR, An (Note 1)		1.65 to 1.95	2.8 to 3.0	—	V _{CCA} ×0.35	V
	V _{ILB}	Bn (Note 1)		1.65 to 1.95	2.8 to 3.0	—	0.8	
H-level output voltage	V _{OHA}	V _{IN} = V _{IH} or V _{IL}	I _{OHA} = −100μA	1.65 to 1.95	2.8 to 3.0	V _{CCA} − 0.2	—	V
			I _{OHA} = −6 mA	1.65	2.8 to 3.0	1.15	—	
	V _{OHB}		I _{OHB} = −100 μA	1.65 to 1.95	2.8 to 3.0	V _{CCB} − 0.2	—	
			I _{OHB} = −6 mA	1.65 to 1.95	2.8	2.2	—	
L-level output voltage	V _{OLA}	V _{IN} = V _{IH} or V _{IL}	I _{OLA} = 100 μA	1.65 to 1.95	2.8 to 3.0	—	0.2	V
			I _{OLA} = 6 mA	1.65	2.8 to 3.0	—	0.3	
	V _{OLB}		I _{OLB} = 100 μA	1.65 to 1.95	2.8 to 3.0	—	0.2	
			I _{OLB} = 6 mA	1.65 to 1.95	2.8	—	0.4	
Input leakage current	I _{IA}	V _{INA} = V _{CCA} or GND DIR = HIGH V _{CD} = V _{WP} = V _{CCA}		1.65 to 1.95	2.8 to 3.0	—	±5.0	μA
	I _{IB}	V _{CMD-B} , DAT0, DAT1, DAT2 = V _{CCA} V _{DAT3} = GND DIR = LOW V _{CD} = V _{WP} = V _{CCA}		1.65 to 1.95	2.8 to 3.0	—	±5.0	
Quiescent supply current	I _{CCA}	V _{INA} = V _{CCA} or GND DIR = HIGH V _{CD} = V _{WP} = V _{CCA}		1.65 to 1.95	2.8 to 3.0	—	20	μA

Note 1: An is a host side signal. Bn is a card side signal.

Note: V_{CCB} is supplied from the built-in LDO.

AC Characteristics (Ta = -30 to 85°C, Input: $t_r = t_f = 2.0$ ns)**V_{CCA} = 1.8 ± 0.15 V, V_{CCB} = 2.9 ± 0.1 V**

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Propagation delay time (Bn → An)	t_{pLH} t_{pHL}	Figure 1, Figure 2	1.0	—	8.5	ns
Propagation delay time (An → Bn)	t_{pLH} t_{pHL}	Figure 1, Figure 2	1.0	—	8.5	ns
Propagation delay time (Clk.h → Clk-f)	t_{pLH} t_{pHL}	Figure 1, Figure 2	1.0	—	14	ns
Output Transition Time (An)	t_{TLH} t_{THL}	Figure 1, Figure 2	—	1.5	—	ns
Output Transition Time (Bn)	t_{TLH} t_{THL}	Figure 1, Figure 2	—	1.5	—	ns
Output to output skew	t_{osLH} t_{osHL}	(Note 1)	—	—	0.5	ns

Note 1: Parameter guaranteed by design. ($t_{osLH} = |t_{pLHm} - t_{pLHn}|$, $t_{osHL} = |t_{pHLm} - t_{pHLn}|$)

Note: An is a host side signal. Bn is a card side signal.

V_{CCB} is supplied from the built-in LDO.

Dynamic Switching Characteristics (Ta = 25°C, Input: $t_r = t_f = 2.0$ ns, C_L = 15 pF)

Characteristics		Symbol	Test Condition	V _{CCA} (V)	V _{CCB} (V)	Typ.	Unit
Quiet output maximum dynamic V _{OL}	A → B	V _{OLP}	V _{IH} = V _{CC} , V _{IL} = 0 V (Note 2)	1.8	2.9	0.35	V
	B → A			1.8	2.9	0.25	
Quiet output minimum dynamic V _{OL}	A → B	V _{OLV}	V _{IH} = V _{CC} , V _{IL} = 0 V (Note 2)	1.8	2.9	-0.35	V
	B → A			1.8	2.9	-0.25	
Quiet output maximum dynamic V _{OH}	A → B	V _{OHP}	V _{IH} = V _{CC} , V _{IL} = 0 V (Note 2)	1.8	2.9	3.25	V
	B → A			1.8	2.9	2.05	
Quiet output minimum dynamic V _{OH}	A → B	V _{OHV}	V _{IH} = V _{CC} , V _{IL} = 0 V (Note 2)	1.8	2.9	2.55	V
	B → A			1.8	2.9	1.55	

Note 2: Parameter guaranteed by design.

Note: An is a host side signal. Bn is a card side signal.

Capacitive Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Circuit	V _{CCA} (V)	V _{CCB} (V)	Typ.	Unit
Power dissipation capacitance (Note 3)	C _{PD} A		A → B (DIR = "H")	1.8	2.9	24	pF
			B → A (DIR = "L")	1.8	2.9	22	
	C _{PD} B		A → B (DIR = "H")	1.8	2.9	76	
			B → A (DIR = "L")	1.8	2.9	28	

Note 3: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

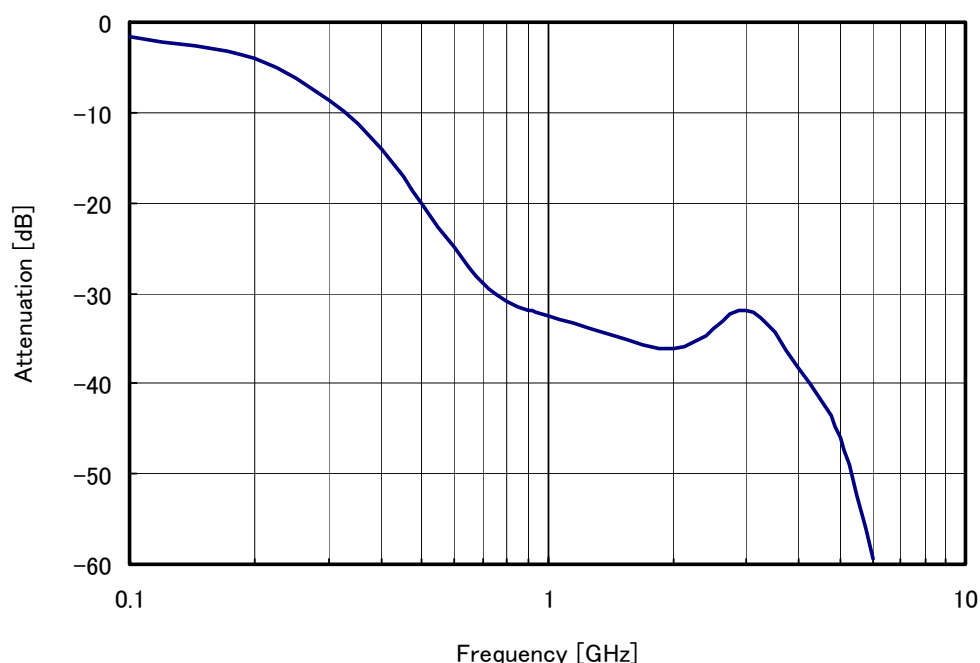
$$I_{CC(opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/6 \text{ (per bit)}$$

Regulator Section

Electrical Characteristics (unless otherwise specified, $V_{IN} = V_{OUT} + 1\text{ V}$, $I_{OUT} = 1\text{ mA}$, $C_{IN} = 0.1\text{ }\mu\text{F}$, $C_{OUT} = 2.2\text{ }\mu\text{F}$, $T_j = 25^\circ\text{C}$)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Input voltage	V_{IN}	—	3.2	—	5.0	V
Output voltage	$V_{CCB}\text{ O/P}$	—	2.8	2.9	3.0	V
Line regulation	Reg·line	$V_{OUT} + 0.5\text{ V} \leq V_{IN} \leq 5.0\text{ V}$, $I_{OUT} = 1\text{ mA}$	—	3	15	mV
Load regulation	Reg·load	$1\text{ mA} \leq I_{OUT} \leq 200\text{ mA}$	—	—	150	mV
Quiescent current	I_{B1}	$I_{OUT} = 0\text{ mA}$	—	40	80	μA
	I_{B2}	$I_{OUT} = 100\text{ mA}$	—	45	85	
Stand-by current	$I_B\text{ (OFF)}$	$V_{CT} = 0\text{ V}$	—	0.1	1.0	μA
Output noise voltage	V_{NO}	$V_{IN} = V_{OUT} + 1\text{ V}$, $I_{OUT} = 10\text{ mA}$, $10\text{ Hz} \leq f \leq 100\text{ kHz}$, $T_a = 25^\circ\text{C}$	—	140	—	μV_{rms}
Temperature coefficient	T_{CVO}	$-40^\circ\text{C} \leq T_{opr} \leq 85^\circ\text{C}$	—	100	—	ppm/ $^\circ\text{C}$
Ripple rejection	R.R.	$V_{IN} = V_{OUT} + 1\text{ V}$, $I_{OUT} = 10\text{ mA}$, $f = 1\text{ kHz}$, $V_{Ripple} = 500\text{ mV}_{p-p}$, $T_a = 25^\circ\text{C}$	—	40	—	dB
Control voltage (ON)	$V_{CT}\text{ (ON)}$	—	1.5	—	V_{IN}	V
Control voltage (OFF)	$V_{CT}\text{ (OFF)}$	—	0	—	0.25	V
Control current (ON)	$I_{CT}\text{ (ON)}$	$V_{CT} = 1.5\text{ V}$	—	—	0.1	μA
Control current (OFF)	$I_{CT}\text{ (OFF)}$	$V_{CT} = 0\text{ V}$	—	—	0.1	μA
Peak output current	$I_{outpeak}$	—	200	—	—	mA

EMI Filter Response (Typical Performance)



Symbol	V _{CC} (output)	
	2.9 ± 0.1 V	1.8 ± 0.18 V
R _L	2 kΩ	2 kΩ
C _L	15 pF	15 pF

AC Waveform

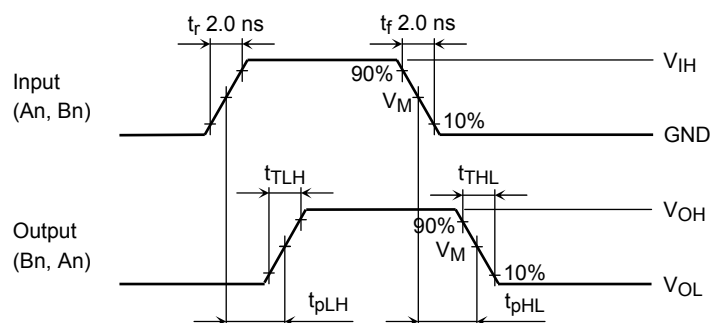
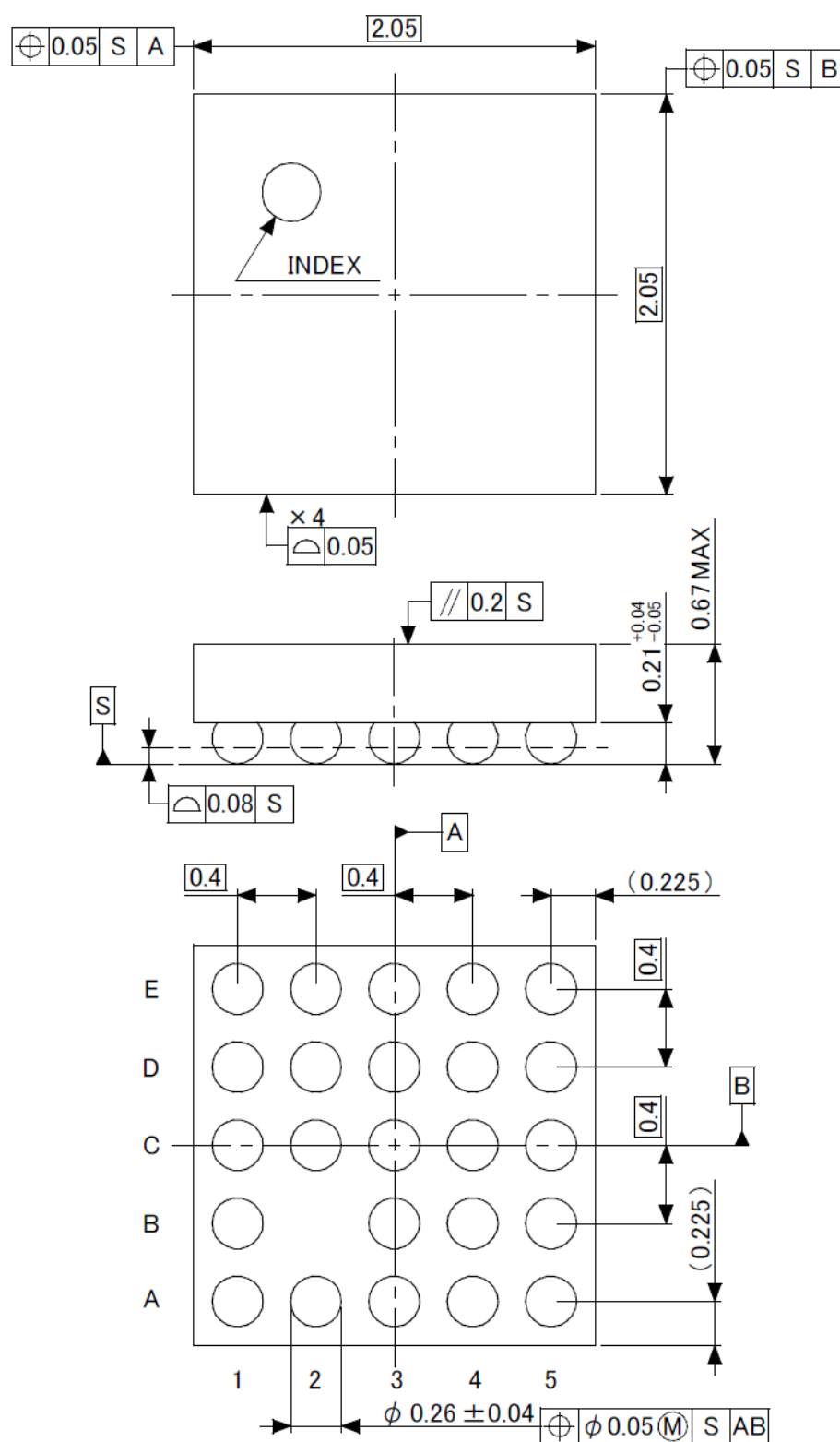


Figure 2 t_{pLH} , t_{pHL} , t_{TLH} , t_{THL}

Symbol	V _{CC}	
	2.9 ± 0.1 V	1.8 ± 0.18 V
V _{IH}	V _{CC}	V _{CC}
V _M	V _{CC} /2	V _{CC} /2

Unit: mm



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